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10/727,817	12/04/2003	Daniel M. Kuchta	YOR920030563US1 (163-23)	7470	
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20 CROSSWAYS PARK NORTH			KIM, DAVID S		
SUITE 210 WOODBURY,	NY 11797		ART UNIT	PAPER NUMBER	
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Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

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	Application No.	Applicant(s)	
Office Action Comments	10/727,817	KUCHTA ET AL.	
Office Action Summary	Examiner	Art Unit	
	David S. Kim	2613	
The MAILING DATE of this communic Period for Reply	ation appears on the cover sheet wi	th the correspondence addi	ess
A SHORTENED STATUTORY PERIOD FO WHICHEVER IS LONGER, FROM THE MA - Extensions of time may be available under the provisions of after SIX (6) MONTHS from the mailing date of this commur - If NO period for reply is specified above, the maximum statu - Failure to reply within the set or extended period for reply wi Any reply received by the Office later than three months afte earned patent term adjustment. See 37 CFR 1.704(b).	ILING DATE OF THIS COMMUNION 37 CFR 1.136(a). In no event, however, may a mication. Itory period will apply and will expire SIX (6) MON III, by statute, cause the application to become AB	CATION. eply be timely filed THS from the mailing date of this come ANDONED (35 U.S.C. § 133).	·
Status			
1) Responsive to communication(s) filed 2a) This action is FINAL. 2b 3) Since this application is in condition for closed in accordance with the practice.	o)⊠ This action is non-final. or allowance except for formal matt	• •	ments is
Disposition of Claims			
4) Claim(s) 1-25 is/are pending in the ap 4a) Of the above claim(s) is/are 5) Claim(s) is/are allowed. 6) Claim(s) 1,2,4,6-11,13,15-22 and 24 is 7) Claim(s) 3,5,12,14,23 and 25 is/are of 8) Claim(s) are subject to restriction Application Papers 9) The specification is objected to by the 10) The drawing(s) filed on is/are: a Applicant may not request that any objection Replacement drawing sheet(s) including the specification is objected to it.	e withdrawn from consideration. s/are rejected. bjected to. on and/or election requirement. Examiner. a) accepted or b) objected to ion to the drawing(s) be held in abeyar the correction is required if the drawing	nce. See 37 CFR 1.85(a). (s) is objected to. See 37 CFR	, ,
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for a) All b) Some * c) None of: 1. Certified copies of the priority do copies of the priority do copies of the priority do copies of the certified copies of application from the International * See the attached detailed Office action	ocuments have been received. ocuments have been received in A f the priority documents have been al Bureau (PCT Rule 17.2(a)).	pplication No received in this National S	tage
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO S) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	O-948) Paper No(s	Summary (PTO-413) S)/Mail Date nformal Patent Application 	

DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-2, 4, 6-11, 13, 15-22, and 24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hogan et al. (U.S. Patent Application Publication No. US 2004/0091268 A1, hereinafter "Hogan") in view of Abe (U.S. Patent No. 5,023,753).

Regarding claim 1, Hogan discloses:

A radio frequency device, comprising:

a signal layer having radio frequency (RF) transmission lines (e.g., RF lines in Fig. 5) disposed over a ground plane (e.g., ground plane in Fig. 5), the RF lines configured and dimensioned to provide impedance matching along the RF lines (impedance matching in paragraph [0037]).

Hogan does not expressly disclose:

a shield formed as a part of the RF lines and disposed below an RF choke of a DC current supply to form an intermediate capacitance between the choke and the shield to control parasitic effects.

However, the usage of a shield between electrical components is an extremely common practice in the art, as exemplified by Abe (center layer in Figs. 2 and 5). At the time the invention was made, it would have been obvious to one of ordinary skill in the art to introduce shielding to various locations in the device of Abe, including below the RF choke of Hogan (Hogan, 34 in Figures). One of ordinary skill in the art would have been motivated to do this to reduce unnecessary radiation that may be generated by the influence of interference waves (Hogan, col. 1, l. 14-24). Additionally, notice that the teachings of Abe could also be implemented with the benefit of controlling parasitic effects (e.g., Abe, "no bad influence" by parasitic/stray capacitance C1 and C3).

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Regarding claim 2, Hogan in view of Abe discloses:

The device as recited in claim 1, wherein the device includes an optical transceiver having a laser biased by the DC current supply (Hogan, BIAS in Fig. 5).

Regarding claim 4, Hogan in view of Abe does not expressly disclose:

The device as recited in claim 1, wherein a balance between the intermediate capacitance versus the parasitic effects is achieved to provide a flat or peaked transmission response over a selected frequency range.

However, this limitation does not significantly limit the claimed invention since the device of Hogan in view of Abe would inherently have some kind of transmission response over a selected frequency range, and such responses are generally flat or peaked over a selected frequency range.

Regarding claim 6, Hogan in view of Abe discloses:

The transceiver as recited in claim 1, further comprising a submount for supporting the choke (Hogan, notice the physical mounting structure of choke 34 in the Figures).

Regarding claim 7, Hogan in view of Abe discloses:

The transceiver as recited in claim 1, wherein the RF line supplies AC signals to a laser diode (Hogan, AC RF signals in paragraph [0037]).

Regarding claim 8, Hogan in view of Abe discloses:

The transceiver as recited in claim 7, further comprising a lens (Hogan, lens 28 or 216 in the Figures) to focus light output from the laser diode.

Regarding claim 9, Hogan in view of Abe discloses:

The transceiver as recited in claim 1, further comprising a photodiode (Hogan, e.g., monitor photodiode 29; also, notice receiver portion 3 that would generally comprise a photodiode as the optical receiver).

Regarding claim 10, Hogan in view of Abe discloses:

An optical transceiver, comprising:

a substrate having a signal layer formed thereon, the signal layer having radio frequency (RF) transmission lines (Hogan, e.g., RF lines in Fig. 5) disposed over a ground plane (Hogan, e.g., ground

plane in Fig. 5), the RF lines configured and dimensioned to provide impedance matching along the RF lines (Hogan, impedance matching in paragraph [0037]), the RF lines having a portion forming a shield (discussion of shield in view of Abe above);

the shield being disposed below an RF choke of a DC current supply to form an intermediate capacitance between the choke and the shield to control parasitic effects (discussion of shield in view of Abe above); and

a laser modulated in accordance with RF signals transmitted by the RF lines (Hogan, paragraph [0037]).

Regarding claim 11, Hogan in view of Abe discloses:

The transceiver as recited in claim 10, wherein the laser is biased by the DC current supply (Hogan, BIAS in Fig. 5).

Regarding claim 13, Hogan in view of Abe does not expressly disclose:

The transceiver as recited in claim 10, wherein a balance between the intermediate capacitance versus the parasitic effects is achieved to provide a flat or peaked transmission response over a selected frequency range.

However, this limitation does not significantly limit the claimed invention since the transceiver of Hogan in view of Abe would inherently have some kind of transmission response over a selected frequency range, and such responses are generally flat or peaked over a selected frequency range.

Regarding claim 15, Hogan in view of Abe discloses:

The transceiver as recited in claim 10, further comprising a submount for supporting the choke (Hogan, notice the physical mounting structure of choke 34 in the Figures).

Regarding claim 16, Hogan in view of Abe discloses:

The transceiver as recited in claim 10, further comprising a lens (Hogan, lens 28 or 216 in the Figures) to focus light output from the laser.

Regarding claim 17, Hogan in view of Abe discloses:

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The transceiver as recited in claim 1, further comprising a photodiode (Hogan, e.g., monitor photodiode 29; also, notice receiver portion 3 that would generally comprise a photodiode as the optical receiver).

Regarding claim 18, Hogan in view of Abe discloses:

A method for fabricating a transceiver, which simultaneously provides impedance matched transmission for radio frequency (RF) and shields against transmission losses due to parasitic effects, comprising the steps of:

identifying parasitic electromagnetic elements associated with an RF choke for a given placement on a substrate (in view of the discussion of Abe above, one could compensate the effect of the parasitic/stray elements associated with RF choke 34 of Hogan); and

placing and dimensioning RF lines on the bench to form impedance matched RF lines (Hogan, impedance matching in paragraph [0037]) wherein a portion of the RF lines shield (see the discussion of the placement of shielding below RF choke 34 of Hogan in view of Abe above) the RF choke for a given bandwidth (any suitable bandwidth) such that impedance matching (Hogan, impedance matching in paragraph [0037]) and control of parasitic effects (Abe, see discussion of parasitic/stray effects above) of the RF choke are simultaneously (the simultaneous provision of these effects would be expected in the combination of Hogan and Abe) provided.

Regarding claim 19, Hogan in view of Abe does not expressly disclose:

The method as recited in claim 18, further comprising the step of iteratively modifying the placing and dimensioning of the RF lines to meet specifications.

However, such an iterative step is a common manufacturing step in the fabrication of devices. At the time the invention was made, it would have been obvious to one of ordinary skill in the art to include such a step in the fabrication of a transceiver of Hogan in view of Abe. One of ordinary skill in the art would have been motivated to do this since it is generally known that iterations allow one to compare different versions of a product according to different parameters so that one can eventually achieve desired specifications. This basic and well-known concept of trial and error meets this limitation.

Regarding claim 20, Hogan in view of Abe discloses:

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The method as recited in claim 18, wherein the parasitic effects include a parasitic inductance for an electrical path (an electrical path of Hogan, e.g., trace lead(s) in paragraphs [0037-0038] inherently include a parasitic inductance) from the RF choke to a laser and a parasitic capacitance (the configuration of the RF choke set apart from the ground plane constitutes a parasitic/stray capacitance, as similarly shown by C2 in Fig. 2 of Abe) between the RF choke and ground plane.

Regarding claim 21, Hogan in view of Abe discloses:

The method as recited in claim 18, further including a submount (Hogan, notice the physical mounting structure of choke 34 in the Figures) for the RF choke and further comprising the step of modifying the RF choke submount location such that a parasitic capacitance of the RF choke to ground is shielded (e.g., see the discussion of the placement of shielding below RF choke 34 of Hogan in view of Abe above).

Regarding claim 22, Hogan in view of Abe discloses:

The method as recited in claim 18, wherein the transceiver is an optical transceiver (Hogan, transceiver in paragraph [0031]).

Regarding claim 24, Hogan in view of Abe does not expressly disclose:

The method as recited in claim 23, further comprising balancing between the intermediate capacitance versus the parasitic effects to provide a flat or peaked transmission response over a selected frequency range.

However, this limitation does not significantly limit the claimed invention since the transceiver of Hogan in view of Abe would inherently have some kind of transmission response over a selected frequency range, and such responses are generally flat or peaked over a selected frequency range.

Allowable Subject Matter

3. **Claims 3, 5, 12, 14, 23, and 25** are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

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Conclusion

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4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Riebman is cited to show a shield (16 in Fig. 5) below an RF choke of a DC current supply. Yamamoto et al. is cited to show a choke circuit with a shield layer(s) between various layers (Fig. 2). Wang et al. is cited to show circuitry that reduces RF signal leakage into a bias circuit and a power supply (Figs. 3-4D). Buer is cited to show examples of circuitry with an RF choke of a DC current supply (e.g., Figs. 1-2).

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David S. Kim whose telephone number is 571-272-3033. The examiner can normally be reached on Mon.-Fri. 9 AM to 5 PM (EST).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kenneth N. Vanderpuye can be reached on 571-272-3078. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

DSK

KENNETH VANDERPUYE SUPERVISORY PATENT EXAMINER